



Welcome to **E-XFL.COM**

Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Active
Programmable Type	In System Programmable
Delay Time tpd(1) Max	5.4 ns
Voltage Supply - Internal	2.5V, 3.3V
Number of Logic Elements/Blocks	570
Number of Macrocells	440
Number of Gates	-
Number of I/O	160
Operating Temperature	0°C ~ 85°C (TJ)
Mounting Type	Surface Mount
Package / Case	256-BGA
Supplier Device Package	256-FBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epm570f256c5

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

MAX II devices are available in space-saving FineLine BGA, Micro FineLine BGA, and thin quad flat pack (TQFP) packages (refer to Table 1–3 and Table 1–4). MAX II devices support vertical migration within the same package (for example, you can migrate between the EPM570, EPM1270, and EPM2210 devices in the 256-pin FineLine BGA package). Vertical migration means that you can migrate to devices whose dedicated pins and JTAG pins are the same and power pins are subsets or supersets for a given package across device densities. The largest density in any package has the highest number of power pins; you must lay out for the largest planned density in a package to provide the necessary power pins for migration. For I/O pin migration across densities, cross reference the available I/O pins using the device pin-outs for all planned densities of a given package type to identify which I/O pins can be migrated. The Quartus® II software can automatically cross-reference and place all pins for you when given a device migration list.

Table 1-3. MAX II Packages and User I/O Pins

Device	68-Pin Micro FineLine BGA (1)	100-Pin Micro FineLine BGA (1)	100-Pin FineLine BGA	100-Pin TQFP	144-Pin TQFP	144-Pin Micro FineLine BGA (1)	256-Pin Micro FineLine BGA (1)	256-Pin FineLine BGA	324-Pin FineLine BGA
EPM240	_	80	80	80	_	_	_	_	_
EPM240G									
EPM570	_	76	76	76	116	_	160	160	_
EPM570G									
EPM1270	_	_	_	_	116	_	212	212	_
EPM1270G									
EPM2210	_	_	_	_	_	_	_	204	272
EPM2210G									
EPM240Z	54	80	_	_	_	_	_	_	_
EPM570Z	_	76	_	_		116	160	_	_

Note to Table 1-3:

Table 1-4. MAX II TQFP, FineLine BGA, and Micro FineLine BGA Package Sizes

Package	68-Pin Micro FineLine BGA	100-Pin Micro FineLine BGA	100-Pin FineLine BGA	100-Pin TQFP	144-Pin TQFP	144-Pin Micro FineLine BGA	256-Pin Micro FineLine BGA	256-Pin FineLine BGA	324-Pin FineLine BGA
Pitch (mm)	0.5	0.5	1	0.5	0.5	0.5	0.5	1	1
Area (mm2)	25	36	121	256	484	49	121	289	361
Length × width (mm × mm)	5 × 5	6 × 6	11 × 11	16 × 16	22 × 22	7×7	11 × 11	17 × 17	19 × 19

⁽¹⁾ Packages available in lead-free versions only.

MAX II devices have an internal linear voltage regulator which supports external supply voltages of 3.3 V or 2.5 V, regulating the supply down to the internal operating voltage of 1.8 V. MAX IIG and MAX IIZ devices only accept 1.8 V as the external supply voltage. MAX IIZ devices are pin-compatible with MAX IIG devices in the 100-pin Micro FineLine BGA and 256-pin Micro FineLine BGA packages. Except for external supply voltage requirements, MAX II and MAX II G devices have identical pin-outs and timing specifications. Table 1–5 shows the external supply voltages supported by the MAX II family.

Table 1-5. MAX II External Supply Voltages

Devices	EPM240 EPM570 EPM1270 EPM2210	EPM240G EPM570G EPM1270G EPM2210G EPM240Z EPM570Z <i>(1)</i>
MultiVolt core external supply voltage (V _{ccint}) (2)	3.3 V, 2.5 V	1.8 V
MultiVolt I/O interface voltage levels (Vccio)	1.5 V, 1.8 V, 2.5 V, 3.3 V	1.5 V, 1.8 V, 2.5 V, 3.3 V

Notes to Table 1-5:

- (1) MAX IIG and MAX IIZ devices only accept 1.8 V on their VCCINT pins. The 1.8-V VCCINT external supply powers the device core directly.
- (2) MAX II devices operate internally at 1.8 V.

Referenced Documents

This chapter references the following documents:

- DC and Switching Characteristics chapter in the MAX II Device Handbook
- MAX II Logic Element to Macrocell Conversion Methodology white paper

Document Revision History

Table 1–6 shows the revision history for this chapter.

Table 1-6. Document Revision History

Date and Revision	Changes Made	Summary of Changes
August 2009, version 1.9	■ Updated Table 1–2.	Added information for speed grade –8
October 2008, version 1.8	Updated "Introduction" section.Updated new Document Format.	_
December 2007,	■ Updated Table 1–1 through Table 1–5.	Updated document with MAX IIZ information.
version1.7	Added "Referenced Documents" section.	
December 2006, version 1.6	Added document revision history.	_
August 2006, version 1.5	Minor update to features list.	_
July 2006, version 1.4	Minor updates to tables.	_

Table 2-1. MAX II Device Resources

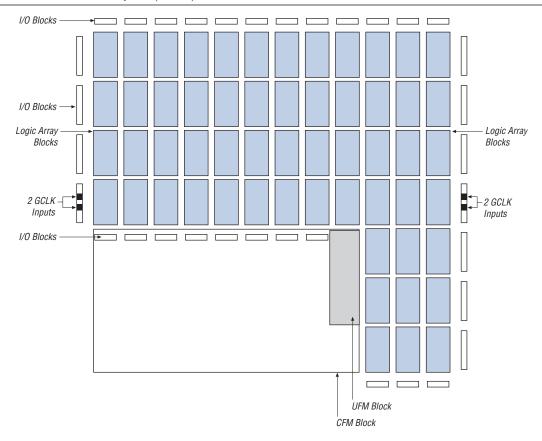
			LAB		
Devices	UFM Blocks	LAB Columns	Long LAB Rows Short LAB Row (Width) (1)		Total LABs
EPM240	1	6	4	_	24
EPM570	1	12	4	3 (3)	57
EPM1270	1	16	7	3 (5)	127
EPM2210	1	20	10	3 (7)	221

Note to Table 2-1:

(1) The width is the number of LAB columns in length.

Figure 2–2 shows a floorplan of a MAX II device.

Figure 2–2. MAX II Device Floorplan (Note 1)



Note to Figure 2-2:

(1) The device shown is an EPM570 device. EPM1270 and EPM2210 devices have a similar floorplan with more LABs. For EPM240 devices, the CFM and UFM blocks are located on the left side of the device.

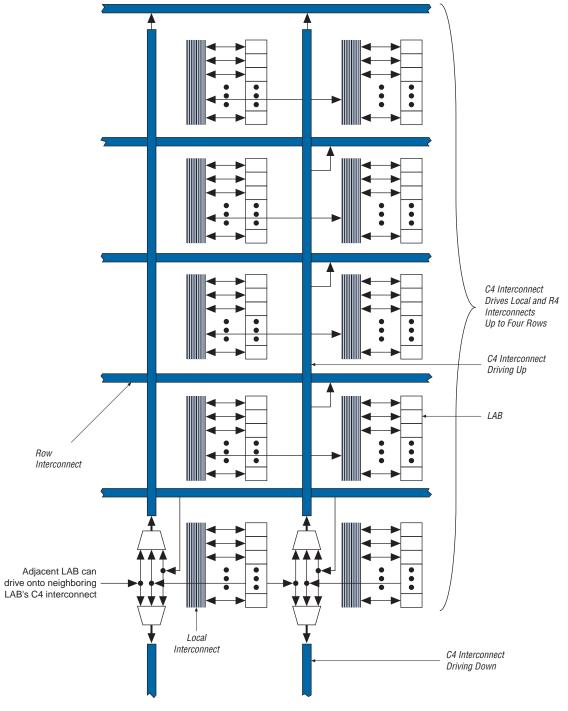
functions from LE 1 to LE 10 in the same LAB. The register chain connection allows the register output of one LE to connect directly to the register input of the next LE in the LAB for fast shift registers. The Quartus II Compiler automatically takes advantage of these resources to improve utilization and performance. Figure 2–11 shows the LUT chain and register chain interconnects.

Local Interconnect Routing Among LEs in the LAB LE0 LUT Chain Register Chain Routing to Routing to Adjacent Adjacent LE LE's Register Input LE1 Local LE2 Interconnect LE3 LE4 LE5 LE6 LE7 LE8

Figure 2-11. LUT Chain and Register Chain Interconnects

The C4 interconnects span four LABs up or down from a source LAB. Every LAB has its own set of C4 interconnects to drive either up or down. Figure 2–12 shows the C4 interconnect connections from an LAB in a column. The C4 interconnects can drive and be driven by column and row IOEs. For LAB interconnection, a primary LAB or its vertical LAB neighbor can drive a given C4 interconnect. C4 interconnects can drive each other to extend their range as well as drive row interconnects for column-to-column connections.

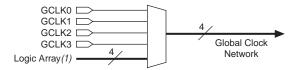
Figure 2–12. C4 Interconnect Connections (Note 1)



Note to Figure 2–12:

(1) Each C4 interconnect can drive either up or down four rows.

Figure 2–13. Global Clock Generation

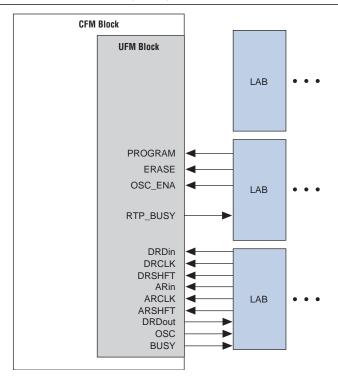


Note to Figure 2-13:

(1) Any I/O pin can use a MultiTrack interconnect to route as a logic array-generated global clock signal.

The global clock network drives to individual LAB column signals, LAB column clocks [3..0], that span an entire LAB column from the top to the bottom of the device. Unused global clocks or control signals in a LAB column are turned off at the LAB column clock buffers shown in Figure 2–14. The LAB column clocks [3..0] are multiplexed down to two LAB clock signals and one LAB clear signal. Other control signal types route from the global clock network into the LAB local interconnect. See "LAB Control Signals" on page 2–5 for more information.

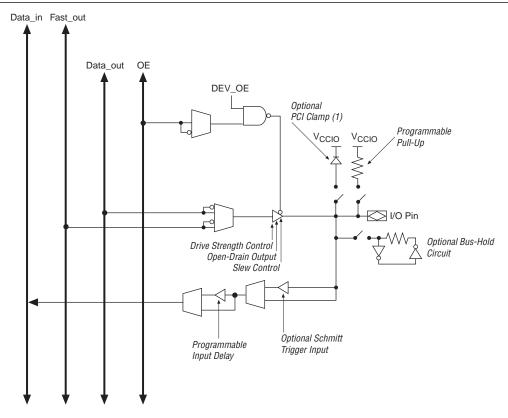
Figure 2–16. EPM240 UFM Block LAB Row Interface (Note 1)



Note to Figure 2–16:

(1) The UFM block inputs and outputs can drive to/from all types of interconnects, not only DirectLink interconnects from adjacent row LABs.

Figure 2–19. MAX II IOE Structure



Note to Figure 2-19:

(1) Available in EPM1270 and EPM2210 devices only.

I/O Blocks

The IOEs are located in I/O blocks around the periphery of the MAX II device. There are up to seven IOEs per row I/O block (5 maximum in the EPM240 device) and up to four IOEs per column I/O block. Each column or row I/O block interfaces with its adjacent LAB and MultiTrack interconnect to distribute signals throughout the device. The row I/O blocks drive row, column, or DirectLink interconnects. The column I/O blocks drive column interconnects.

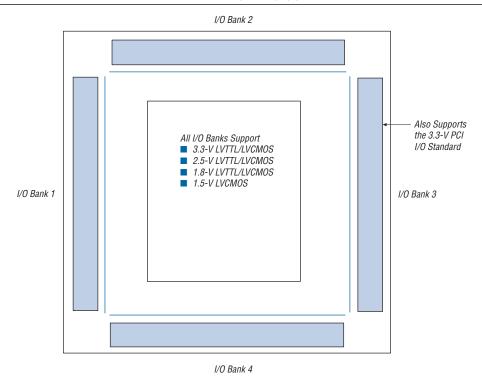


Figure 2–23. MAX II I/O Banks for EPM1270 and EPM2210 (Note 1), (2)

Notes to Figure 2-23:

- (1) Figure 2–23 is a top view of the silicon die.
- (2) Figure 2-23 is a graphical representation only. Refer to the pin list and the Quartus II software for exact pin locations.

Each I/O bank has dedicated V_{CCIO} pins that determine the voltage standard support in that bank. A single device can support 1.5-V, 1.8-V, 2.5-V, and 3.3-V interfaces; each individual bank can support a different standard. Each I/O bank can support multiple standards with the same V_{CCIO} for input and output pins. For example, when V_{CCIO} is 3.3 V, Bank 3 can support LVTTL, LVCMOS, and 3.3-V PCI. V_{CCIO} powers both the input and output buffers in MAX II devices.

The JTAG pins for MAX II devices are dedicated pins that cannot be used as regular I/O pins. The pins TMS, TDI, TDO, and TCK support all the I/O standards shown in Table 2–4 on page 2–27 except for PCI. These pins reside in Bank 1 for all MAX II devices and their I/O standard support is controlled by the V_{CCIO} setting for Bank 1.

PCI Compliance

The MAX II EPM1270 and EPM2210 devices are compliant with PCI applications as well as all 3.3-V electrical specifications in the *PCI Local Bus Specification Revision 2.2*. These devices are also large enough to support PCI intellectual property (IP) cores. Table 2–5 shows the MAX II device speed grades that meet the PCI timing specifications.

Connect VCCIO pins to either a 1.5-V, 1.8 V, 2.5-V, or 3.3-V power supply, depending on the output requirements. The output levels are compatible with systems of the same voltage as the power supply (that is, when VCCIO pins are connected to a 1.5-V power supply, the output levels are compatible with 1.5-V systems). When VCCIO pins are connected to a 3.3-V power supply, the output high is 3.3 V and is compatible with 3.3-V or 5.0-V systems. Table 2–7 summarizes MAX II MultiVolt I/O support.

Table 2–7. MAX II MultiVolt I/O Support (Note 1)

		. !	Input Signa	I		Output Signal						
VCCIO (V)	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V		
1.5	✓	✓	✓	✓	_	✓	_	_	_	_		
1.8	✓	✓	✓	✓	_	√ (2)	✓	_	_	_		
2.5	_	_	✓	✓	_	√ (3)	√ (3)	✓	_	_		
3.3	_	_	√ (4)	✓	√ (5)	√ (6)	√ (6)	√ (6)	✓	√ (7)		

Notes to Table 2-7:

- (1) To drive inputs higher than V_{CCIO} but less than 4.0 V including the overshoot, disable the I/O clamp diode. However, to drive 5.0-V inputs to the device, enable the I/O clamp diode to prevent V_1 from rising above 4.0 V.
- (2) When $V_{CCIO} = 1.8 \text{ V}$, a MAX II device can drive a 1.5-V device with 1.8-V tolerant inputs.
- (3) When $V_{CCIO} = 2.5$ V, a MAX II device can drive a 1.5-V or 1.8-V device with 2.5-V tolerant inputs.
- (4) When $V_{CCIO} = 3.3 \text{ V}$ and a 2.5-V input signal feeds an input pin, the VCCIO supply current will be slightly larger than expected.
- (5) MAX II devices can be 5.0-V tolerant with the use of an external resistor and the internal I/O clamp diode on the EPM1270 and EPM2210 devices.
- (6) When $V_{CCIO} = 3.3$ V, a MAX II device can drive a 1.5-V, 1.8-V, or 2.5-V device with 3.3-V tolerant inputs.
- (7) When V_{CCIO} = 3.3 V, a MAX II device can drive a device with 5.0-V TTL inputs but not 5.0-V CMOS inputs. In the case of 5.0-V CMOS, open-drain setting with internal I/O clamp diode (available only on EPM1270 and EPM2210 devices) and external resistor is required.
 - For information about output pin source and sink current guidelines, refer to the *AN* 428: *MAX II CPLD Design Guidelines*.

Referenced Documents

This chapter referenced the following documents:

- AN 428: MAX II CPLD Design Guidelines
- DC and Switching Characteristics chapter in the MAX II Device Handbook
- Hot Socketing and Power-On Reset in MAX II Devices chapter in the MAX II Device Handbook
- Using User Flash Memory in MAX II Devices chapter in the MAX II Device Handbook

JTAG Instruction	Instruction Code	Description						
CLAMP (1)	00 0000 1010	Places the 1-bit bypass register between the TDI and TDO pins, which allows the boundary scan test data to pass synchronously through selected devices to adjacent devices during normal device operation, while holding I/O pins to a state defined by the data in the boundary-scan register.						
USER0	00 0000 1100	This instruction allows you to define the scan chain between TDI and TDO in the MAX II logic array. This instruction is also used for custom logic and JTAG interfaces.						
USER1	00 0000 1110	This instruction allows you to define the scan chain between TDI and TDO in the MAX II logic array. This instruction is also used for custom logic and JTAG interfaces.						
IEEE 1532	(2)	IEEE 1532 ISC instructions used when programming a MAX II device						

Table 3–1. MAX II JTAG Instructions (Part 2 of 2)

Notes to Table 3-1:

- (1) HIGHZ, CLAMP, and EXTEST instructions do not disable weak pull-up resistors or bus hold features.
- (2) These instructions are shown in the 1532 BSDL files, which will be posted on the Altera® website at www.altera.com when they are available.

via the JTAG port.



Unsupported JTAG instructions should not be issued to the MAX II device as this may put the device into an unknown state, requiring a power cycle to recover device operation.

The MAX II device instruction register length is 10 bits and the USERCODE register length is 32 bits. Table 3–2 and Table 3–3 show the boundary-scan register length and device IDCODE information for MAX II devices.

Table 3-2. MAX II Boundary-Scan Register Length

Device	Boundary-Scan Register Length
EPM240	240
EPM570	480
EPM1270	636
EPM2210	816

Table 3-3. 32-Bit MAX II Device IDCODE (Part 1 of 2)

		Binary IDCODE (32	2 Bits) <i>(1)</i>		
Device	Version (4 Bits)	Part Number	Manufacturer Identity (11 Bits)	LSB (1 Bit) <i>(2)</i>	HEX IDCODE
EPM240	0000	0010 0000 1010 0001	000 0110 1110	1	0x020A10DD
EPM240G					
EPM570	0000	0010 0000 1010 0010	000 0110 1110	1	0x020A20DD
EPM570G					
EPM1270	0000	0010 0000 1010 0011	000 0110 1110	1	0x020A30DD
EPM1270G					
EPM2210	0000	0010 0000 1010 0100	000 0110 1110	1	0x020A40DD
EPM2210G					

MAX II Device Flash Altera FPGA **Memory Device** CONF DONE DQ[7..0] DQ[7..0] nSTATUS A[20..0] A[20..0] nCE OE OE WF WF CE CE RY/BY RY/BY DATA0 **nCONFIG** TDO_U Parallel **DCLK** TDI TDI U Flash Loader TMS TMS_U Configuration TCK_U

SHIFT U CLKDR_U

UPDATE_U RUNIDLE_U USER1_U

Figure 3–1. MAX II Parallel Flash Loader

Notes to Figure 3-1:

- This block is implemented in LEs.
- (2) This function is supported in the Quartus II software.

TDO

In System Programmability

MAX II devices can be programmed in-system via the industry standard 4-pin IEEE Std. 1149.1 (JTAG) interface. In-system programmability (ISP) offers quick, efficient iterations during design development and debugging cycles. The logic, circuitry, and interconnects in the MAX II architecture are configured with flash-based SRAM configuration elements. These SRAM elements require configuration data to be loaded each time the device is powered. The process of loading the SRAM data is called configuration. The on-chip configuration flash memory (CFM) block stores the SRAM element's configuration data. The CFM block stores the design's configuration pattern in a reprogrammable flash array. During ISP, the MAX II JTAG and ISP circuitry programs the design pattern into the CFM block's non-volatile flash array.

Logic

(1), (2)

The MAX II JTAG and ISP controller internally generate the high programming voltages required to program the CFM cells, allowing in-system programming with any of the recommended operating external voltage supplies (that is, 3.3 V/2.5 V or 1.8 V for the MAX IIG and MAX IIZ devices). ISP can be performed anytime after V_{CCINT} and all V_{CCIO} banks have been fully powered and the device has completed the configuration power-up time. By default, during in-system programming, the I/O pins are tri-stated and weakly pulled-up to V_{CIO} to eliminate board conflicts. The insystem programming clamp and real-time ISP feature allow user control of I/O state or behavior during ISP.

For more information, refer to "In-System Programming Clamp" on page 3-6 and "Real-Time ISP" on page 3–7.

These devices also offer an ISP_DONE bit that provides safe operation when insystem programming is interrupted. This ISP_DONE bit, which is the last bit programmed, prevents all I/O pins from driving until the bit is programmed.

I/O Pins Remain Tri-Stated during Power-Up

A device that does not support hot-socketing may interrupt system operation or cause contention by driving out before or during power-up. In a hot socketing situation, the MAX II device's output buffers are turned off during system power-up. MAX II devices do not drive out until the device attains proper operating conditions and is fully configured. Refer to "Power-On Reset Circuitry" on page 4–5 for information about turn-on voltages.

Signal Pins Do Not Drive the V_{cco} or V_{ccint} Power Supplies

MAX II devices do not have a current path from I/O pins or GCLK[3..0] pins to the V_{CCIO} or V_{CCINT} pins before or during power-up. A MAX II device may be inserted into (or removed from) a system board that was powered up without damaging or interfering with system-board operation. When hot socketing, MAX II devices may have a minimal effect on the signal integrity of the backplane.

AC and DC Specifications

You can power up or power down the V_{CCIO} and V_{CCINT} pins in any sequence. During hot socketing, the I/O pin capacitance is less than 8 pF. MAX II devices meet the following hot socketing specifications:

- The hot socketing DC specification is: $|I_{IOPIN}| < 300 \,\mu\text{A}$.
- The hot socketing AC specification is: $|I_{IOPIN}|$ < 8 mA for 10 ns or less.



MAX II devices are immune to latch-up when hot socketing. If the TCK JTAG input pin is driven high during hot socketing, the current on that pin might exceed the specifications above.

 I_{IOPIN} is the current at any user I/O pin on the device. The AC specification applies when the device is being powered up or powered down. This specification takes into account the pin capacitance but not board trace and external loading capacitance. Additional capacitance for trace, connector, and loading must be taken into consideration separately. The peak current duration due to power-up transients is 10 ns or less.

The DC specification applies when all V_{CC} supplies to the device are stable in the powered-up or powered-down conditions.

Hot Socketing Feature Implementation in MAX II Devices

The hot socketing feature turns off (tri-states) the output buffer during the power-up event (either V_{CCINT} or V_{CCIO} supplies) or power-down event. The hot-socket circuit generates an internal HOTSCKT signal when either V_{CCINT} or V_{CCIO} is below the threshold voltage during power-up or power-down. The HOTSCKT signal cuts off the output buffer to make sure that no DC current (except for weak pull-up leaking) leaks through the pin. When V_{CC} ramps up very slowly during power-up, V_{CC} may still be relatively low even after the power-on reset (POR) signal is released and device configuration is complete.

Power-Up Timing

Table 5–12 shows the power-up timing characteristics for MAX II devices.

Table 5–12. MAX II Power-Up Timing

Symbol	Parameter	Device	Min	Тур	Max	Unit
t _{config} (1)	The amount of time from when	EPM240	_	_	200	μs
	minimum V_{CCINT} is reached until the device enters user mode (2)	EPM570	_	_	300	μs
	the device effects user filloue (2)	EPM1270	_	_	300	μs
		EPM2210	_	_	450	μs

Notes to Table 5-12:

(1) Table 5–12 values apply to commercial and industrial range devices. For extended temperature range devices, the t_{config} maximum values are as follows:

 Device
 Maximum

 EPM240
 300 μs

 EPM570
 400 μs

 EPM1270
 400 μs

 EPM2210
 500 μs

Power Consumption

Designers can use the Altera® PowerPlay Early Power Estimator and PowerPlay Power Analyzer to estimate the device power.



For more information about these power analysis tools, refer to the *Understanding and Evaluating Power in MAX II Devices* chapter in the *MAX II Device Handbook* and the *PowerPlay Power Analysis* chapter in volume 3 of the *Quartus II Handbook*.

Timing Model and Specifications

MAX II devices timing can be analyzed with the Altera Quartus® II software, a variety of popular industry-standard EDA simulators and timing analyzers, or with the timing model shown in Figure 5–2.

MAX II devices have predictable internal delays that enable the designer to determine the worst-case timing of any design. The software provides timing simulation, point-to-point delay prediction, and detailed timing analysis for device-wide performance evaluation.

⁽²⁾ For more information about POR trigger voltage, refer to the Hot Socketing and Power-On Reset in MAX II Devices chapter in the MAX II Device Handbook

Internal Timing Parameters

Internal timing parameters are specified on a speed grade basis independent of device density. Table 5–15 through Table 5–22 describe the MAX II device internal timing microparameters for logic elements (LEs), input/output elements (IOEs), UFM blocks, and MultiTrack interconnects. The timing values for -3, -4, and -5 speed grades shown in Table 5–15 through Table 5–22 are based on an EPM1270 device target, while -6, -7, and -8 speed grade values are based on an EPM570Z device target.



For more explanations and descriptions about each internal timing microparameters symbol, refer to the *Understanding Timing in MAX II Devices* chapter in the *MAX II Device Handbook*.

Table 5–15. LE Internal Timing Microparameters

			MAX II / MAX IIG							M <i>A</i>	X IIZ			
		−3 S _l Gra	peed ide		peed ade		Speed ade		Speed rade		Speed ade		Speed ade	
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t _{LUT}	LE combinational LUT delay	_	571	_	742	_	914	_	1,215	_	2,247	_	2,247	ps
t _{comb}	Combinational path delay	_	147	_	192	_	236	_	243	_	305	_	309	ps
t _{CLR}	LE register clear delay	238	_	309	_	381	_	401	_	541	_	545	_	ps
t _{PRE}	LE register preset delay	238	_	309	_	381	_	401	_	541	_	545	_	ps
t _{su}	LE register setup time before clock	208	_	271	_	333	_	260	_	319	_	321	_	ps
t _H	LE register hold time after clock	0	_	0	_	0	_	0	_	0	_	0	_	ps
t _{co}	LE register clock- to-output delay	_	235		305	_	376	_	380	_	489	_	494	ps
t _{CLKHL}	Minimum clock high or low time	166	_	216	_	266	_	253	_	335	_	339	_	ps
t _c	Register control delay	_	857		1,114		1,372	_	1,356	_	1,722	_	1,741	ps

Table 5–17. t_{ZX} IOE Microparameter Adders for Fast Slew Rate (Part 2 of 2)

MAX II / MAX IIG														
		1	peed ade	-4 Speed Grade		–5 Speed Grade		-6 Speed Grade		-7 Speed Grade		–8 Speed Grade		
Standard		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
1.5-V LVCMOS	4 mA	_	1,118	_	1,454	_	1,789	_	580	_	588	_	588	ps
	2 mA	_	2,410	_	3,133	_	3,856	_	915	_	923	_	923	ps
3.3-V PCI	20 mA	_	19	_	25	_	31	_	72	_	71	_	74	ps

Table 5–18. t_{ZX} IOE Microparameter Adders for Slow Slew Rate

MAX II / MAX IIG							MAX IIZ							
			–3 Speed Grade		–4 Speed Grade		–5 Speed Grade		-6 Speed Grade		Speed ade	–8 Speed Grade		
Standard		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
3.3-V LVTTL	16 mA	_	6,350	_	6,050	_	5,749	_	5,951	_	5,952	_	6,063	ps
	8 mA	_	9,383	_	9,083	_	8,782	_	6,534	_	6,533	_	6,662	ps
3.3-V LVCMOS	8 mA	_	6,350	_	6,050	_	5,749	_	5,951	_	5,952	_	6,063	ps
	4 mA		9,383	_	9,083	_	8,782	_	6,534	_	6,533	_	6,662	ps
2.5-V LVTTL /	14 mA	_	10,412	_	10,112	_	9,811	_	9,110	_	9,105	_	9,237	ps
LVCMOS	7 mA	_	13,613	_	13,313	_	13,012	_	9,830	_	9,835	_	9,977	ps
3.3-V PCI	20 mA	_	-75	_	-97	_	-120	_	6,534	_	6,533	_	6,662	ps

Table 5–19. $t_{\chi\chi}$ IOE Microparameter Adders for Fast Slew Rate

	MAX II / MAX IIG							MAX IIZ						
		1	-3 Speed Grade		-4 Speed Grade		–5 Speed Grade		-6 Speed Grade		peed ade	–8 Speed Grade		
Standard		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
3.3-V LVTTL	16 mA	_	0	_	0	_	0	_	0	_	0	_	0	ps
	8 mA	_	-56	_	-72	_	-89	_	-69	_	-69	_	-69	ps
3.3-V LVCMOS	8 mA	_	0	_	0	_	0	_	0	_	0	_	0	ps
	4 mA	_	-56	_	-72	_	-89	_	-69	_	-69	_	-69	ps
2.5-V LVTTL /	14 mA	_	-3	_	-4	_	- 5	_	-7	_	-11	_	-11	ps
LVCMOS	7 mA	_	-4 7	_	-61	_	-75	_	-66	_	-70	_	-70	ps
1.8-V LVTTL /	6 mA	_	119	_	155	_	191	_	45	_	34	_	37	ps
LVCMOS	3 mA	_	207	_	269	_	331	_	34	_	22	_	25	ps
1.5-V LVCMOS	4 mA	_	606	_	788	_	970	_	166	_	154	_	155	ps
	2 mA	_	673	_	875	_	1,077	_	190	_	177	_	179	ps
3.3-V PCI	20 mA	_	71	_	93	_	114	_	-69	_	-69	_	-69	ps

Figure 5-4. UFM Program Waveforms

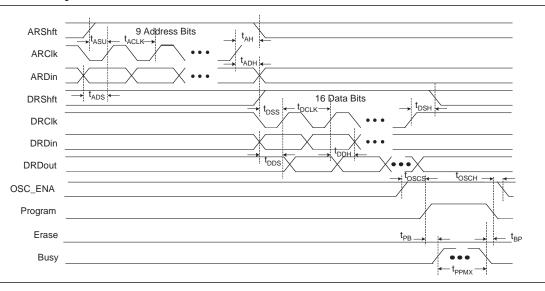


Figure 5–5. UFM Erase Waveform

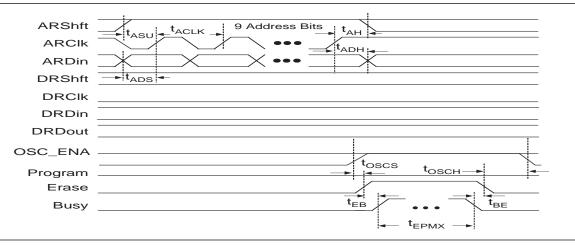


Table 5–22. Routing Delay Internal Timing Microparameters

		MAX II / MAX IIG						MAX IIZ						
	−3 Speed Grade		-4 Speed Grade		-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		-8 Speed Grade			
Routing	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit	
t _{C4}	-	429	_	556	_	687	_	(1)	_	(1)	_	(1)	ps	
t _{R4}	-	326	_	423	_	521	_	(1)	_	(1)	_	(1)	ps	
t _{local}	-	330	_	429	-	529	_	(1)	_	(1)	_	(1)	ps	

Note to Table 5-22:

(1) The numbers will only be available in a later revision.

Table 5-33. MAX II Maximum Output Clock Rate for I/O

		ı	MAX II / MAX II	G	MAX IIZ					
I/O Standard		-3 Speed Grade	-4 Speed Grade	–5 Speed Grade	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade			
3.3-V LVTTL	304	304	304	304	304	304	MHz			
3.3-V LVCMOS	304	304	304	304	304	304	MHz			
2.5-V LVTTL	220	220	220	220	220	220	MHz			
2.5-V LVCMOS	220	220	220	220	220	220	MHz			
1.8-V LVTTL	200	200	200	200	200	200	MHz			
1.8-V LVCMOS	200	200	200	200	200	200	MHz			
1.5-V LVCMOS	150	150	150	150	150	150	MHz			
3.3-V PCI	304	304	304	304	304	304	MHz			

JTAG Timing Specifications

Figure 5–6 shows the timing waveforms for the JTAG signals.

Figure 5-6. MAX II JTAG Timing Waveforms

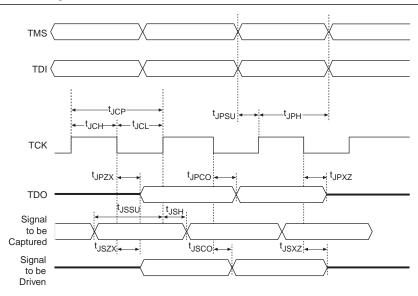


Table 5–34 shows the JTAG Timing parameters and values for MAX II devices.

Table 5–34. MAX II JTAG Timing Parameters (Part 1 of 2)

Symbol	Parameter	Min	Max	Unit
t _{JCP} (1)	TCK clock period for $V_{\text{CCIO1}} = 3.3 \text{ V}$	55.5	_	ns
	TCK clock period for $V_{\text{CCIO1}} = 2.5 \text{ V}$	62.5	_	ns
	TCK clock period for $V_{CCIO1} = 1.8 \text{ V}$	100	_	ns
	TCK clock period for $V_{CCIO1} = 1.5 \text{ V}$	143	_	ns
t _{JCH}	TCK clock high time	20	_	ns
t _{JCL}	TCK clock low time	20	_	ns



6. Reference and Ordering Information

MII51006-1.6

Software

MAX® II devices are supported by the Altera® Quartus® II design software with new, optional MAX+PLUS® II look and feel, which provides HDL and schematic design entry, compilation and logic synthesis, full simulation and advanced timing analysis, and device programming. Refer to the Design Software Selector Guide for more details about the Quartus II software features.

The Quartus II software supports the Windows XP/2000/NT, Sun Solaris, Linux Red Hat v8.0, and HP-UX operating systems. It also supports seamless integration with industry-leading EDA tools through the NativeLink interface.

Device Pin-Outs

Printed device pin-outs for MAX II devices are available on the Altera website (www.altera.com).

Ordering Information

Figure 6–1 describes the ordering codes for MAX II devices. For more information about a specific package, refer to the *Package Information* chapter in the *MAX II Device Handbook*.

Figure 6-1. MAX II Device Packaging Ordering Information

